

Micropower Voltage References

FEATURES

- Guaranteed ±4mV initial accuracy LT1004-1.2
- Guaranteed ± 20mV accuracy LT1004-2.5
- Guaranteed 10µA operating current
- Guaranteed temperature performance
- Operates up to 20mA
- Very low dynamic impedance

APPLICATIONS

- Portable meter references
- Portable test instruments
- Battery operated systems
- Current loop instrumentation

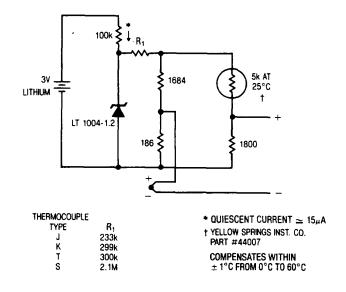
DESCRIPTION

The LT1004 Micropower Voltage References are two terminal bandgap reference diodes designed to provide high accuracy and excellent temperature characteristics at very low operating currents. Optimization of the key parameters in the design, processing and testing of the device results in accuracy specifications previously attainable only with selected units. Below is a distribution plot of reference voltage for a typical lot of LT1004-1.2. Virtually all of the units fall well within the prescribed limits of ± 4 mV.

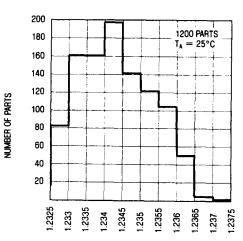
The LT1004 is a pin for pin replacement for the 385 series of references with improved accuracy specifications. More important, the LT1004 is an attractive device for use in systems where accuracy was previously obtained at the expense of power consumption and trimming.

For a low drift micropower reference with guaranteed temperature coefficient, see the LT1034CS8 data sheet.

Micropower Cold Junction Compensation For Thermocouples

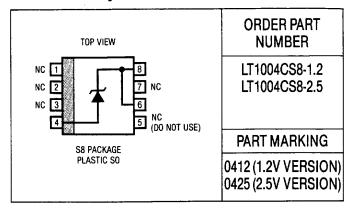


Typical Distribution of Reference Voltage (LT1004-1.2)



ABSOLUTE MAXIMUM RATINGS

PACKAGE/ORDER INFORMATION



ELECTRICAL CHARACTERISTICS (See Note 1)

SYMBOL	PARAMETER	CONDITIONS		LT1004-1.2 Min Typ Max			LT1004-2.5 Min Typ Max			UNITS
Vz	Reverse Breakdown Voltage	$I_R = 100 \mu A$ LT1004C 0°C $\leq T_A \leq 70$ °C	•	1.231 1.225	1.235 1.235	1.239 1.245	2.480 2.470	2.500 2.500	2.520 2.530	
7 Temb	Average Temperature Coefficient	$I_{min} \leq I_{R} \leq 20mA$			20			20		ppm/°C
I _{min}	Minimum Operating Current		•		8	10		12	20	μА
71 ⁸	Reverse Breakdown Voltage Change with Current	$I_{min} \leqslant I_R \leqslant 1mA$ $1mA \leqslant I_R \leqslant 20mA$	•			1 1.5 10 20			1 1.5 10 20	mV mV mV
rz	Reverse Dynamic Impedance	$I_R = 100 \mu A$	•		0.2	0.6 1.5		0.2	0.6 1.5	Ω
e _n	Wide Band Noise (RMS)	$I_R = 100 \mu A$ $10Hz \le f \le 10kHz$			60			120		μ۷
∠V _Z Time	Long Term Stability	$I_R = 100 \mu A$ $T_A = 25^{\circ}C \pm 0.1^{\circ}C$			20			20		ppm/kHr

The lacktriangle denotes the specifications which apply over the full operating temperature range.

Note 1: All specifications are for $T_A = 25^{\circ}C$ unless otherwise noted.